

SavantIC Semiconductor

Product Specification

Silicon PNP Power Transistors

TIP30/30A/30B/30C

DESCRIPTION

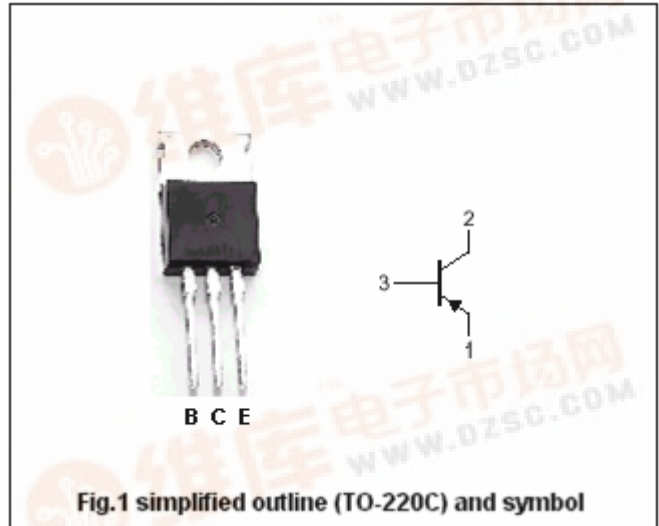
- With TO-220C package
- Complement to type TIP29/29A/29B/29C

APPLICATIONS

- For use in general purpose power amplifier and switching applications

PINNING

PIN	DESCRIPTION
1	Emitter
2	Collector;connected to mounting base
3	Base



ABSOLUTE MAXIMUM RATINGS(T_C=25°C)

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT	
V _{CBO}	Collector-base voltage	Open emitter	TIP30	-40	V
			TIP30A	-60	
			TIP30B	-80	
			TIP30C	-100	
V _{CEO}	Collector-emitter voltage	Open base	TIP30	-40	V
			TIP30A	-60	
			TIP30B	-80	
			TIP30C	-100	
V _{EBO}	Emitter-base voltage	Open collector	-5	V	
I _C	Collector current (DC)		-1	A	
I _{CM}	Collector current-Pulse		-3	A	
I _B	Base current		-0.4	A	
P _C	Collector power dissipation	T _C =25°C	30	w	
T _j	Junction temperature		150	°C	
T _{stg}	Storage temperature		-65~150	°C	

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CHARACTERISTICS

T_j=25°C unless otherwise specified

SYMBOL	PARAMETER		CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CEO(SUS)}	Collector-emitter sustaining voltage	TIP30	I _C =-30mA; I _B =0	-40			V
		TIP30A		-60			
		TIP30B		-80			
		TIP30C		-100			
V _{CE(sat)}	Collector-emitter saturation voltage		I _C =-1A; I _B =-0.125A			-0.7	V
V _{BE}	Base-emitter on voltage		I _C =-1A; V _{CE} =-4V			-1.3	V
I _{CES}	Collector cut-off current	TIP30	V _{CE} =-40V; V _{EB} =0			-0.2	mA
		TIP30A	V _{CE} =-60V; V _{EB} =0				
		TIP30B	V _{CE} =-80V; V _{EB} =0				
		TIP30C	V _{CE} =-100V; V _{EB} =0				
I _{CEO}	Collector cut-off current	TIP30/30A	V _{CE} =-30V; I _B =0			-0.3	mA
		TIP30B/30C	V _{CE} =-60V; I _B =0				
I _{EBO}	Emitter cut-off current		V _{EB} =-5V; I _C =0			-1.0	mA
h _{FE-1}	DC current gain		I _C =-0.2A; V _{CE} =-4V	40			
h _{FE-2}	DC current gain		I _C =-1A; V _{CE} =-4V	15		75	
f _T	Transition frequency		I _C =-0.2A; V _{CE} =-10V; f=1MHz	3			MHz

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-c}	Thermal resistance junction to case	4.167	°C/W

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PACKAGE OUTLINE

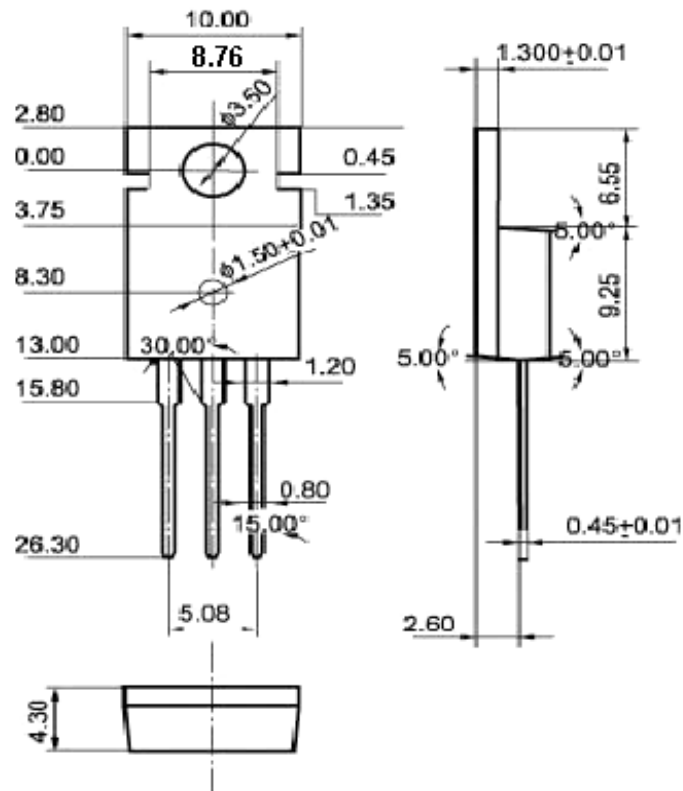


Fig.2 Outline dimensions (unindicated tolerance:±0.10 mm)